

Breaking the switching-speed-limits in various topologies The new 1200V IGBT HighSpeed 3 family, optimized in every respect

The new 1200V 3rd Generation HighSpeed IGBT family is optimized for hard- and soft-switching topologies. The family sets a new benchmark for switching losses and is recommended for use in topologies switching at more than 20kHz.

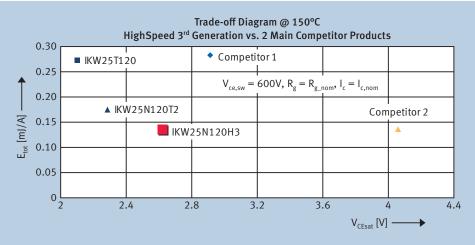
The very short tail-current, and low turn off losses (25% less then the closest competitor) are the key features of this new family and up to 15% efficiency can be attained by implementing this family in your design.

Not only does the family offer very low switching losses, the conduction losses are also very low. This is thanks to the world famous TRENCHSTOPTM technology from Infineon that has an intrinsically very low $V_{ce(sat)}$ behavior.

Meanwhile the free wheeling diode in the duo packs is a 4th generation emitter controlled diode and is optimized for fast recovery whilst maintaining a high level of softness. This provides excellent complementary high speed switching performance, ruggedness and EMI behavior.

Paired with the HighSpeed 3 IGBT you have the best device on the market.

Infineon introduces a new family of 1200V IGBTs optimized for highfrequencyapplications which provide benchmark performance in terms of switching losses and efficiency.



Infineon's new HighSpeed 3 IGBT is perfectly balanced between switching and conduction losses.

Applications

- UPS
- Welding
- Solar inverters

Main Features and Benefits

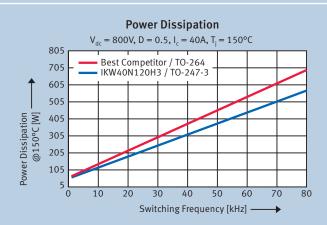
- Lowest switching losses for switching frequencies above 20kHz giving high efficiency
- Soft switching waveforms for excellent EMI behavior
- Low V_{ce(sat)} giving low conduction losses
- Optimized diode for target applications meaning low diode losses and fast recovery time
- RoHS compliant
- Positive V_{ce(sa)} temperature coefficient meaning thermal runaway not an issue and paralleling is easy
- 10µs short circuit rating

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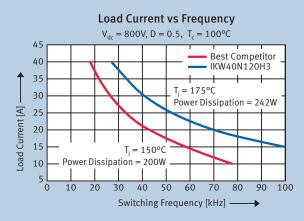


- The new HighSpeed 3 IGBT eliminates the tail-current at turn-off
- Drastically reducing the E_{off} losses



 $\mathsf{P} = \mathsf{V}_{_{ce}} \mathbin{x} \mathsf{I}_{_{c}} \mathbin{x} \mathsf{D} + \mathsf{f}_{_{sw}} \mathbin{x} \mathsf{E}_{_{sw,tot}}$

At 40A, $T_i = 150^{\circ}$ C, the IFX device provides 15% lower losses.



Thanks to the higher T_{jmax} and lower losses, for a fixed $T_c = 100^{\circ}$ C the KW device can run up to 50% higher Load Current than best competitor's device.

		I _{C puls}	P_{tot} (T _c = 25°C)	P_{tot} $(T_c = 100^{\circ}C)$	V _{CE(sat) (typ.)} (25°C)	V _{CE(sat) (typ.)} (175°C)	TO-247 Single	TO-247 DuoPack	Availability
	[A]	[A]	[W]	[W]	[V]	[V]	///	///	
	15	60	217	105	2.05	2.7	IGW15N120H3		Now
	25	75	326	156	2.05	2.7	IGW25N120H3		Now
	40	160	483	220	2.05	2.7	IGW40N120H3		Now
	15	60	217	105	2.05	2.7		IKW15N120H3	Now
	25	75	326	156	2.05	2.7		IKW25N120H3	Now
	40	160	483	220	2.05	2.7		IKW40N120H3	Now

Product Portfolio

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